

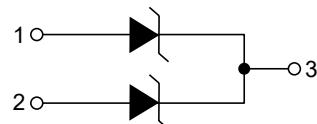
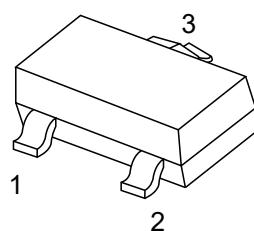
1. Description

The NUP1105L has been designed to protect LIN and single line CAN transceivers from ESD and other harmful transient voltage events. This device provides bidirectional protection for the data line with a single SOT-23 package, giving the system designer a low cost option for improving system reliability .

3. Features

- SOT-23 Package Allows One Separate Bidirectional Configuration
- 350 W Peak Power Dissipation per Line (8 x 20 sec Waveform)
- Low Reverse Leakage Current (< 100 nA)
- ISO 7637-1, Nonrepetitive EMI Surge Pulse TBD
- IEC Compatibility:
 - IEC 61000-4-2 (ESD): Level 4
 - IEC 61000-4-4 (EFT): 40 A – 5/50 ns
 - IEC 61000-4-5 (Lightning) 8.0 A (8/20 μ s)
- ISO 7637-3, Repetitive Electrical Fast Transient (EFT) TBDEMI Surge Pulses

4. Pinning information



SOT-23



5. Absolute Maximum Ratings ($T_J=25^\circ\text{C}$, unless otherwise specified)

| Parameter | Symbol | Value | Units |
|---|----------|------------|------------------|
| Peak Power Dissipation, 8x20 μs Double Exponential Waveform (Note 1) | P_{PK} | 350 | W |
| Junction Temperature Range | T_J | -55 to 150 | $^\circ\text{C}$ |
| Storage Temperature Range | T_J | -55 to 150 | $^\circ\text{C}$ |
| Lead Solder Temperature (10 s) | T_L | 260 | $^\circ\text{C}$ |
| Human Body Model (HBM) | ESD | 16 | kV |
| Machine Model (MM) | | 400 | V |
| IEC 61000-4-2 Specification (Contact) | | 30 | kV |

Notes:

1. Non-repetitive current pulse per Figure 1.



6. Electrical Characteristic ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|----------------------------|-----------|---|------|-----|------|-------|
| Reverse Working Voltage | V_{RWM} | (Note 2) | 24 | | | V |
| Breakdown Voltage | V_{BR} | $I_T=1\text{mA}$ (Note 3) | 25.7 | | 28.4 | V |
| Reverse Leakage Current | I_R | $V_{RWM}=24\text{V}$ | | 15 | 100 | nA |
| Clamping Voltage | V_C | $I_{PP}=5\text{A}$ (8x20 μs Waveform) (Note 4) | | | 40 | V |
| Clamping Voltage | V_C | $I_{PP}=8\text{A}$ (8x20 μs Waveform) (Note 4) | | | 44 | V |
| Maximum Peak Pulse Current | I_{PP} | 8x20 μs Waveform (Note 4) | | | 8 | A |
| Capacitance | C_J | $V_R=0\text{V}$, $f=1\text{MHz}$ (Line to GND) | | | 60 | pF |
| | | $V_R=0\text{V}$, $f=1\text{MHz}$ (Anode to Anode) | | | 30 | pF |

Notes:

- Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
 3. V_{BR} is measured at pulse test current I_T .
 4. Pulse waveform per Figure 1.



8.Typical characteristic

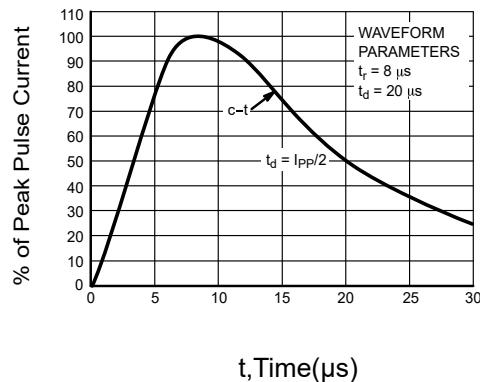
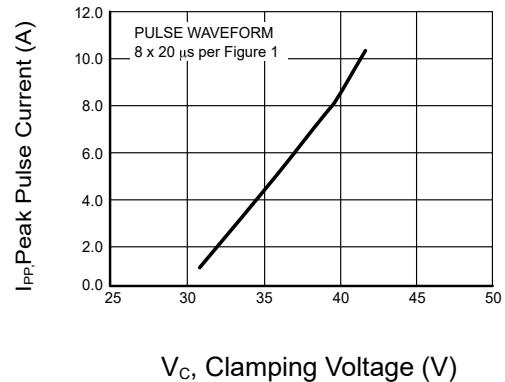
Figure 1: Pulse Waveform, $8 \times 20 \mu s$ 

Figure 2: Clamping Voltage vs Peak Pulse Current

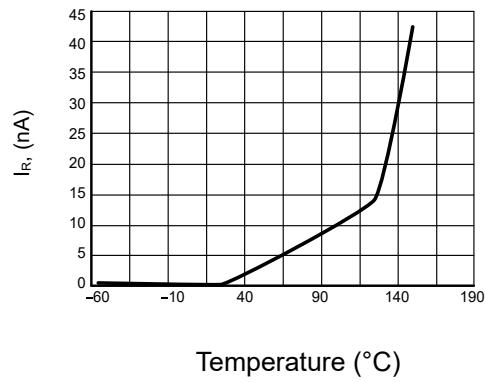
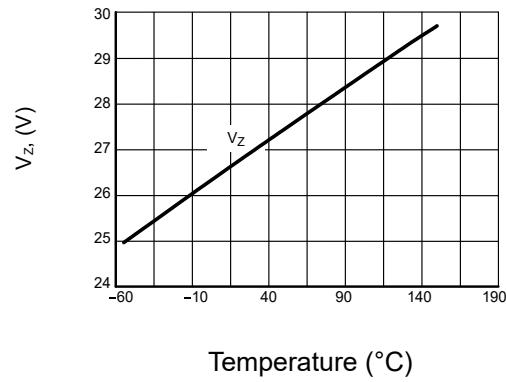
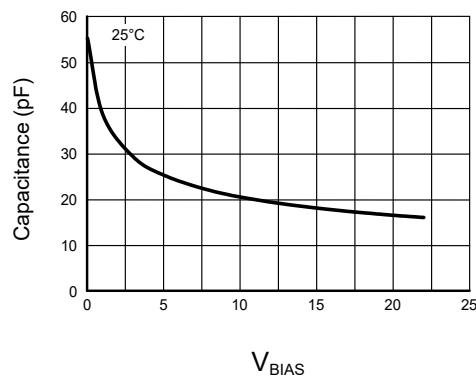
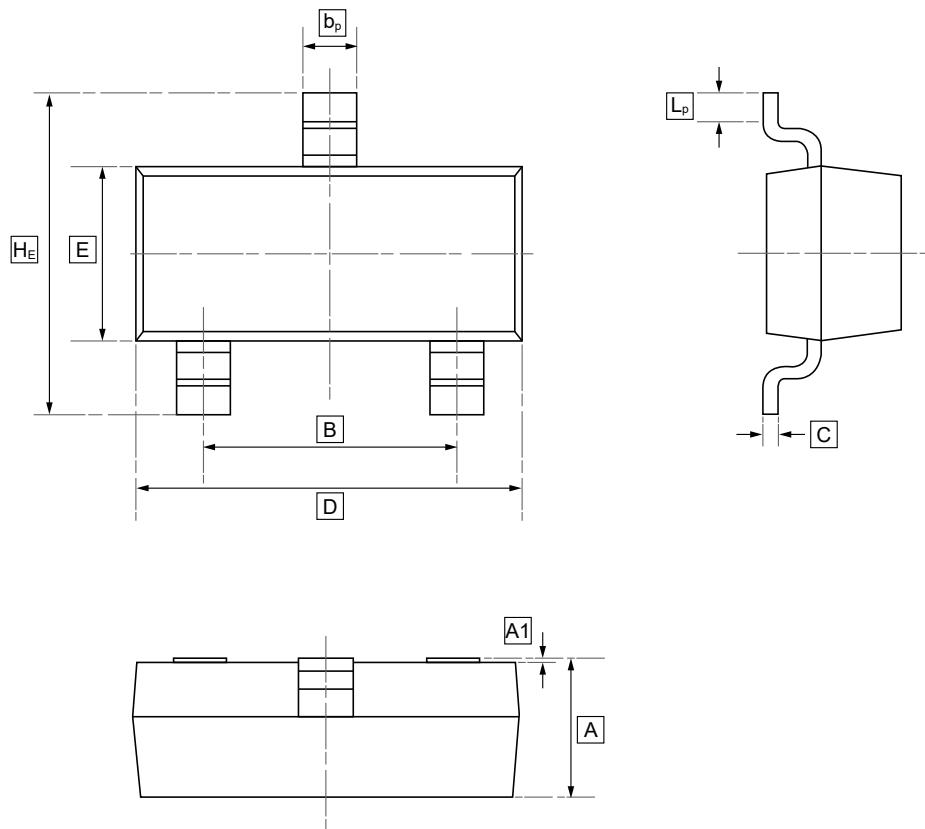


Figure 3: Typical Leakage vs. Temperature

Figure 4: Typical V_Z @ 1.0 mA vs. TemperatureFigure 5: Capacitance vs. V_{BIAS}



9. SOT-23 Package Outline Dimensions

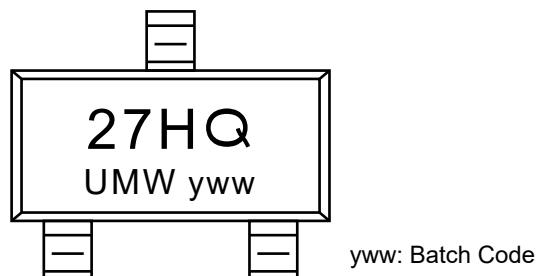


DIMENSIONS (mm are the original dimensions)

| Symbol | A | B | b _p | C | D | E | H _E | A1 | L _p |
|------------|------|------|----------------|------|------|------|----------------|-------|----------------|
| Min | 0.95 | 1.78 | 0.35 | 0.08 | 2.70 | 1.20 | 2.20 | 0.013 | 0.20 |
| Max | 1.40 | 2.04 | 0.50 | 0.19 | 3.10 | 1.65 | 3.00 | 0.100 | 0.50 |



10.Ordering information



| Order Code | Package | Base QTY | Delivery Mode |
|-----------------|---------|----------|---------------|
| UMW NUP1105LT1G | SOT-23 | 3000 | Tape and reel |



11. Disclaimer

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